

150 W High Power Density Adapter Using SJ Si MOSFETs Evolution Board User Manual



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EVAL BOARD USER'S MANUAL

Contents

This evaluation board user manual describes the 150 W High Power Density Adapter and its main parameters like efficiency, no-load input power consumption, EMI signature, transient responses, etc. The evaluation board is dedicated to present ON Semiconductor's high performance controllers. High Power Density design is enabled when using these controllers and higher switching frequency. Higher efficiency can be achieved by using GaN HEMT devices instead of Silicon Super-junction MOSFETs.

The evaluation board comprising of the PFC boost converter operated in the critical conduction mode (CrCM) and LLC power stage. The PFC front stage is driven by NCP1615, assures unity power factor and low input current THD. The LLC stage operates @ 260 to 300 kHz @ nominal load and it's managed by the NCP1399 high performance current mode LLC controller. Super-junction Si MOSFETs (like FCMT199N60) can be assembled as primary side power switches. The CV/CC controller NCP4353A ensures output voltage regulation.

Above mentioned controllers are placed on the Control Module. Secondary side utilizes synchronous rectifier (SR) from NCP4305 or NCP4306 family composed with NVMF55C645NL 4mΩ 60V Power MOSFET. Whole SR stage is implemented on the daughter card for easier main power board PCB design. The discrete or integrated LLC resonant thanks implementations can be used in one board with few changes thanks to universal design.

This evaluation board manual focuses mainly on short description of adapter operation principles and connections. For more detailed information please refer to datasheets of individual part.



Key Features

- Wide Input Voltage Range
- High Power Density, High Efficiency
- Low No-load Power Consumption
- X2 Capacitor Discharge Function
- Near Unity Power Factor
- Overload Protection, Thermal Protection
- Low Mains Operation Protection
- Secondary Short Circuit Protected
- Regulated Output Under any Conditions
- Capability to Implement Off-mode for

Table 1. GENERAL PARAMETERS

Device	Applications	Input Voltage	Normal Output Voltage / Current	Output Power	V _{OUT} Ripple
NCP1615 NCP1399 NCP4305 NCP4353	Notebook Adaptors, Ac – dc converters for consumer electronics	90 – 265 Vac	19 Vdc / 8 A 9 A max limit	150 W	< 250 mV @ Full load
Efficiency	Standby Power	Operating Temperature	Cooling	Topology	Board size
Up to 94.15%	150 mW @ 230 Vac	0 – 50 °C	Passive cooling	PFC CrCM LLC + SR	116 x 55 x 18 mm

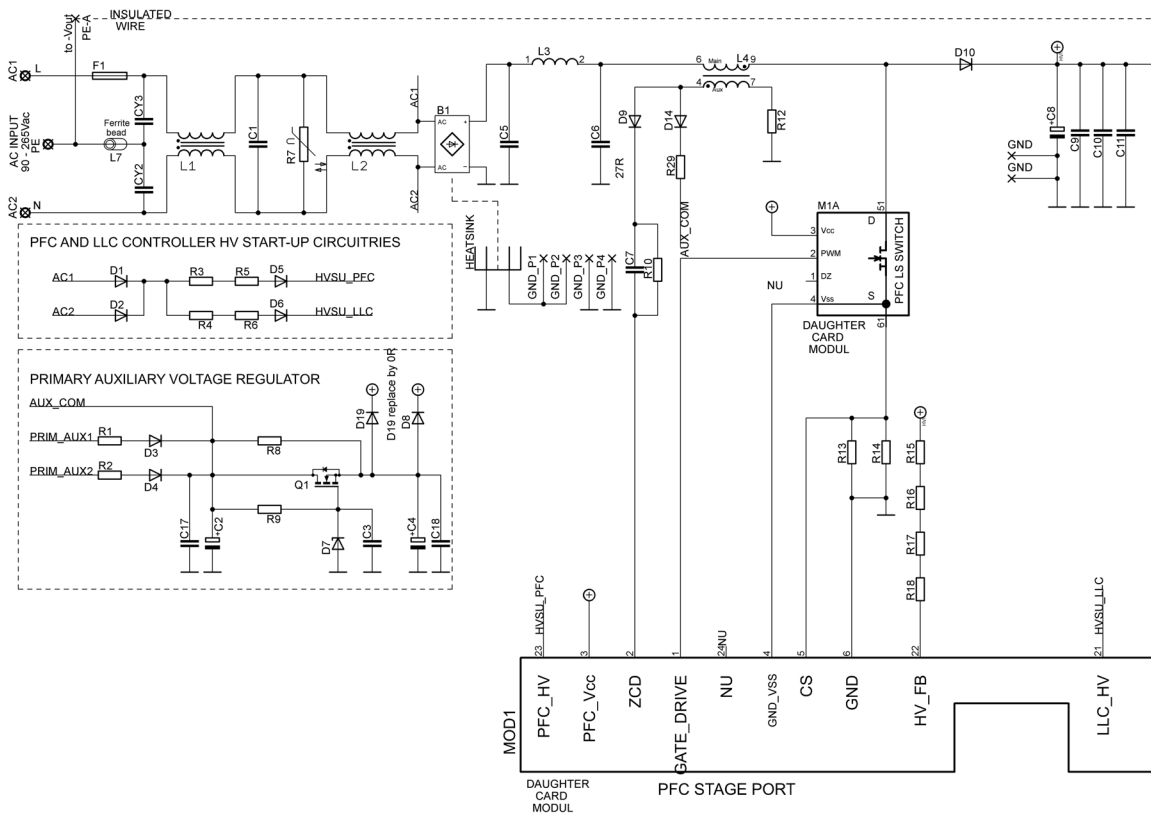


Figure 1. 150 W High Power Density Adapter – Schematic Of The Power-Board (1/2)

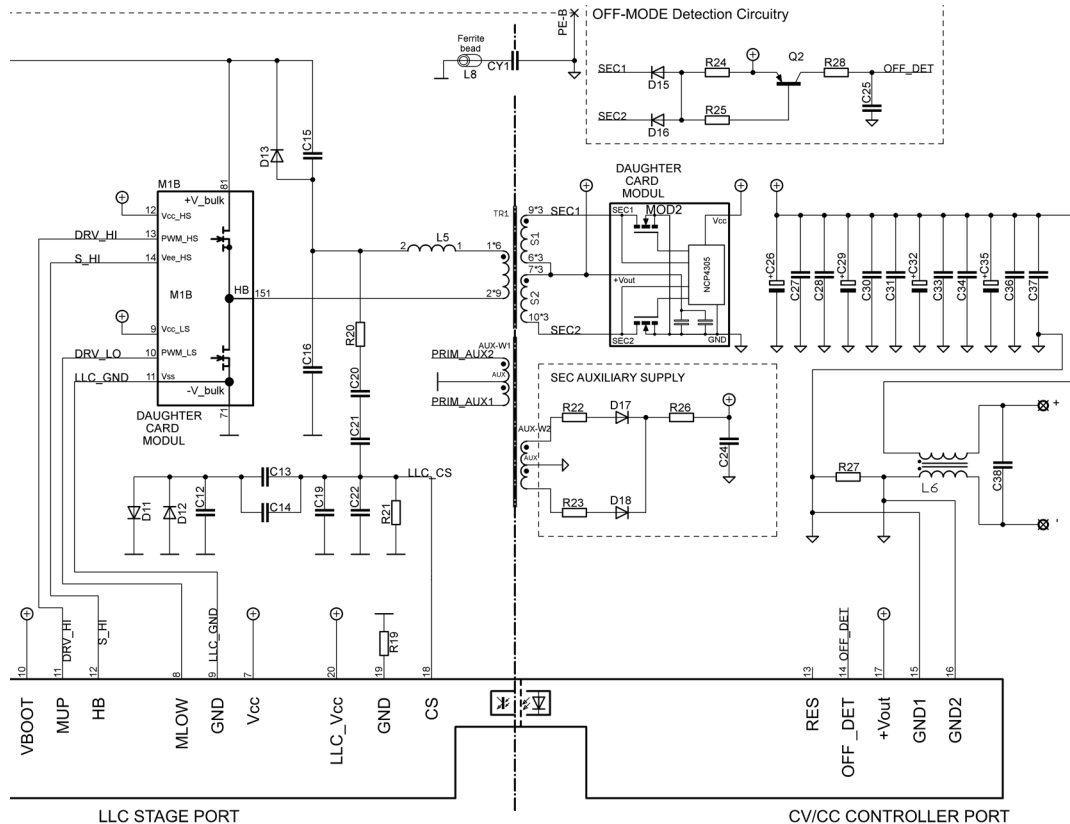


Figure 2. 150 W High Power Density Adapter – Schematic Of The Power-Board (2/2)

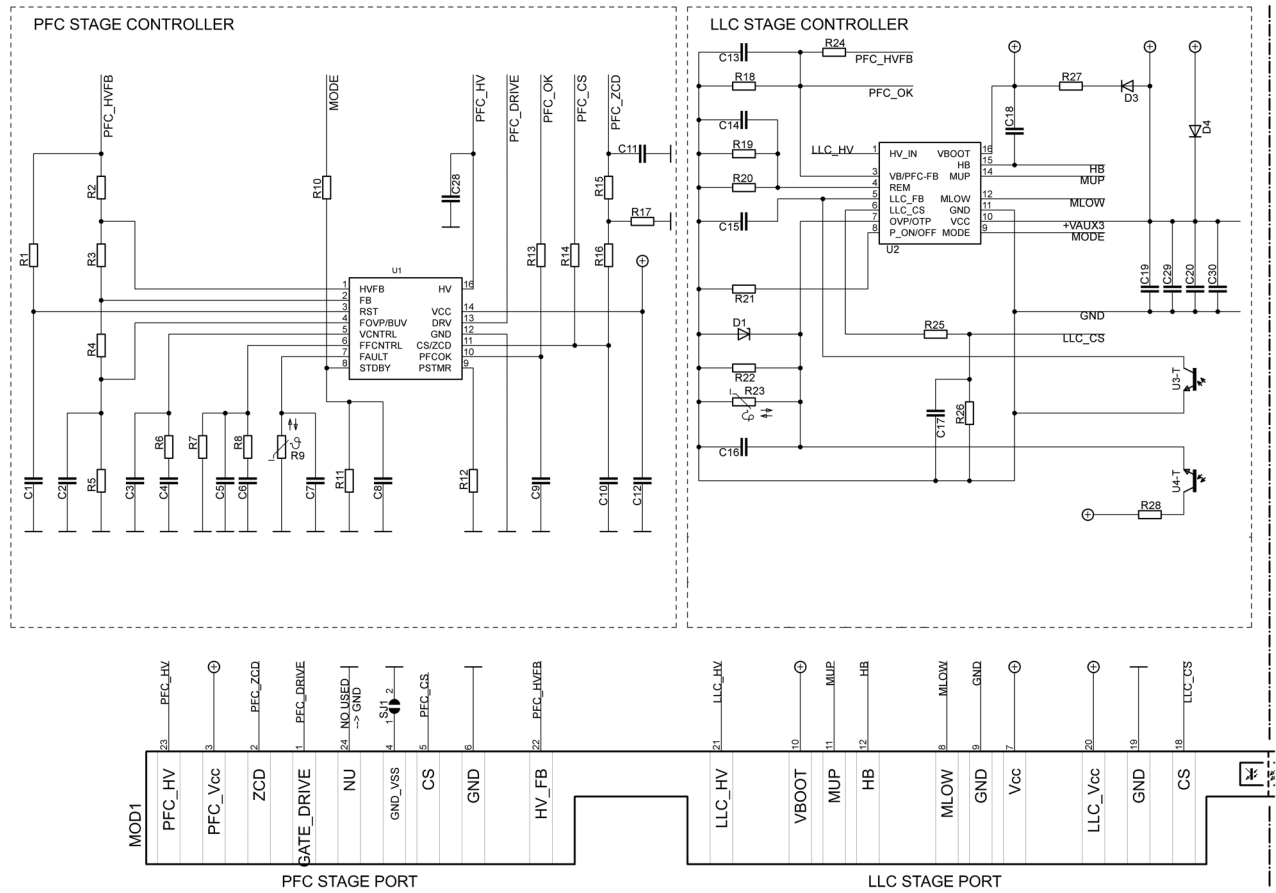


Figure 3. High Power Density Adapter – Schematic Of The Control Module 1/2



Figure 4. High Power Density Adapter – Schematic Of The Control Module 2/2

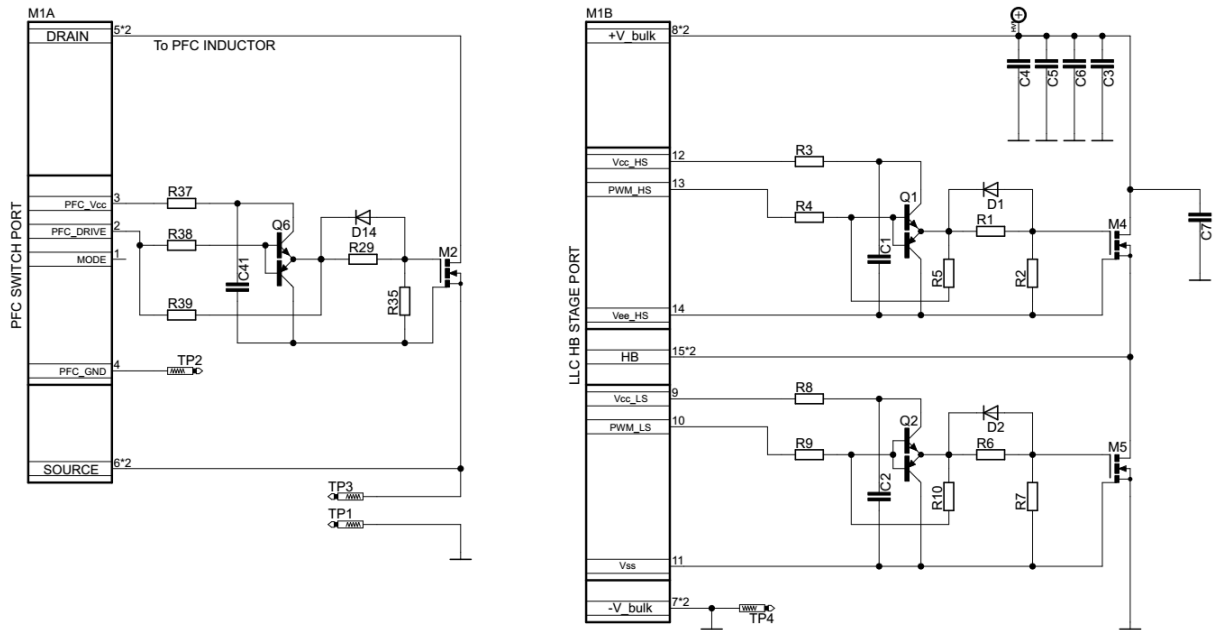


Figure 5. 150 W High Power Density Adapter – Schematic Of The Switch Module With Si MOSFETs

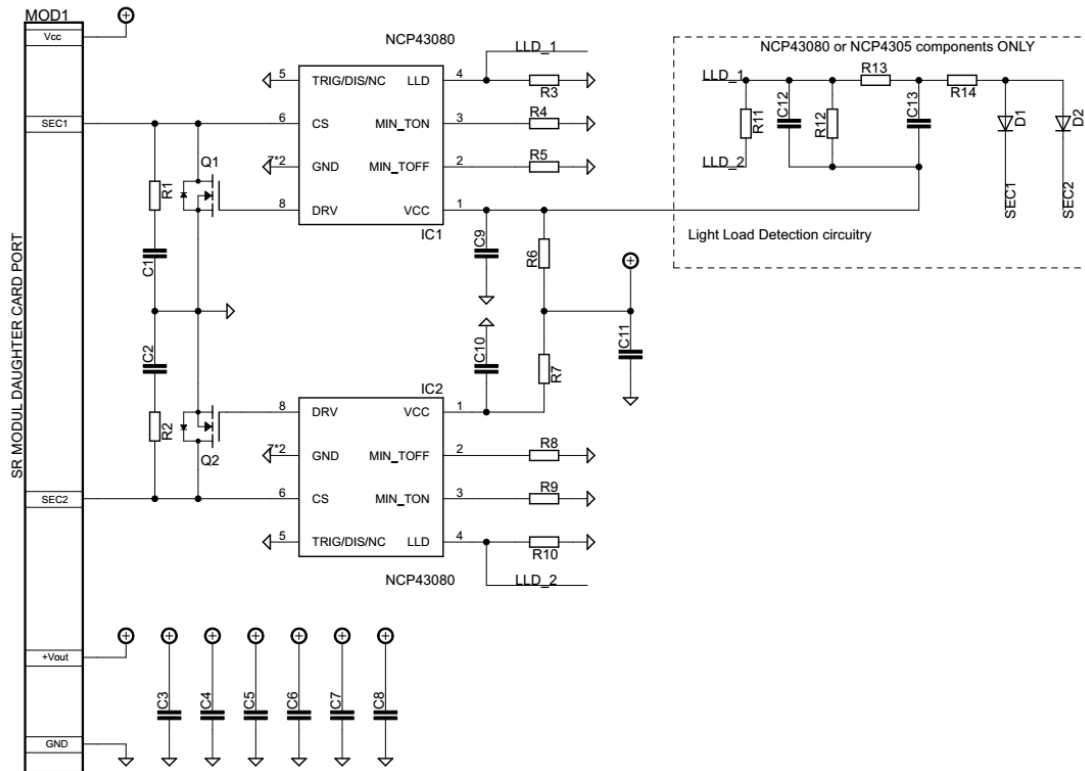


Figure 6. 150 W High Power Density Adapter – Schematic of Synchronous Rectifier Module

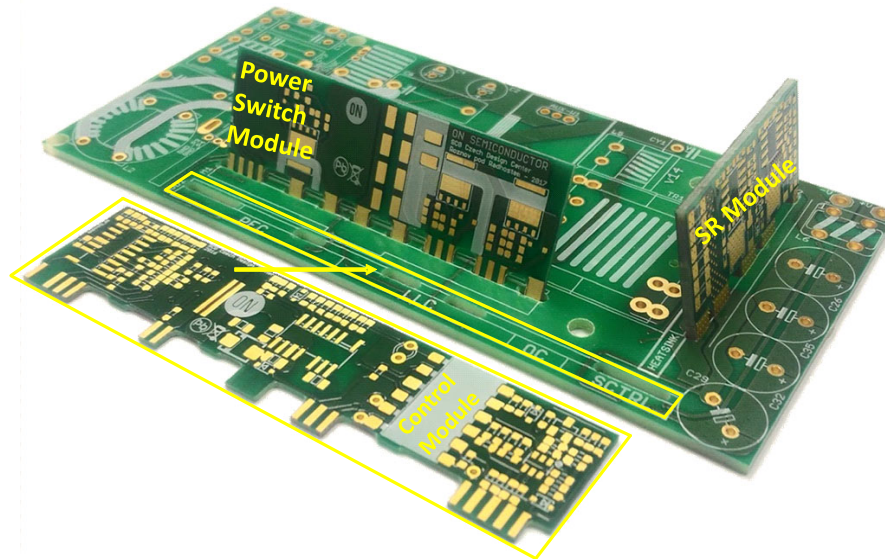


Figure 7. 150 W High Power Density Adapter – Arrangement Of Modules

DETAILED DESCRIPTIONS OF THE EVALUATION BOARD

Adapter modular conceptions – The demo-board is constructed using a main power board plus daughtercards or modules, which are showed in Figure 7. This assists evaluation and allows the user to exchange daughtercards for experimentation. This comprehensive type of construction helps to reduce PCB area, thus increases power density and also allows reducing number of PCB layers. All modules PCBs are designed as 2-layers with 35um or 70um thin copper plating. PCBs with 70um copper plating are used for SR and Power Switch Modules. The lowest PCB manufacturing and assembly cost has been achieved thanks to this construction.

The input of the converter is protected by the varistor R7. A differential mode lightning surge protection has not been optimized. The fuse F1 is 4A time-lag type fuse to withstand the inrush current. The inrush current limiting NTC thermistor is not used in this demo-board (Figure NO TAG.)

The EMI filter consists from the common-mode power line chokes L1 and L2, X2-capacitor C1, and three Y-capacitors CY1 – CY3. CY1 is complemented with ferrite beads L6 at one terminal. The center of CY2 and CY3 capacitors is connected to the PE terminal through ferrite bead L7. The PE-A terminal should be connected to the PE-B terminal by a wire to reduce EMI signature. Pre-filter arranged by polypropylene capacitors C5, C6 and differential mode inductor L3 (Figure NO TAG.) is used for further reduction of EMI signature.

The HV Start-up and X2 discharge capability – both primary controllers are equipped with High Voltage Start-up current sources (NCP1615, NCP1399). PFC High-voltage Start-up (HVSU) is assured via serial circuit R3, R5, D5, and two diodes D1 and D2. Diodes are shared

for PFC and LLC HVSU. LLC HVSU is joined through same serial circuit R4, R6 and D6. To avoid influence between controllers, HV pin of both controllers are separated via mentioned serial circuitries.

Additionally for NCP1615 – the PFC controller has X2 discharge function. The X2-capacitor is discharged after disconnecting power cord from the line.

The PFC front stage implements critical conduction mode PFC boost converter and consists mainly the bulk capacitor C8, which is decoupled at high frequencies (HF) with multi-layer ceramic capacitors (MLCC) C9–11, PFC inductor L4, rectifying diode D10 and power switch (Figure NO TAG.), which is located on Power Switch Module (Figure 5.). The PFC controller NCP1615 senses inductor current directly as a voltage drop on resistors R13, R14. These resistors are connected directly to Control Module, where the PFC controller is located. These resistors define maximum PFC front stage peak current. The PFC controller U1 (NCP1615) uses CS/ZCD for inductor peak current sensing and zero current condition or valley detection. Zero current detection is guaranteed by PFC coil auxiliary winding voltage, which is rectified with D9 and this signal is connected to Control Module via parallel RC circuit R10 and C7. Input voltage is observed at HV pin, which also serves for input voltage sensing and BROWN-OUT protection. The bulk capacitor voltage is fed into PFC controller through set of four resistors R15, R16, R17 and R18. Necessary PFC compensation circuitries and components are located on the Control Module board. The PFC OK status is transferred via network of C9, R13, C13 and R18 to LLC controller, which is subsequently enabled after PFC provides PFC OK status. For more details, please refer to NCP1615 datasheet.

Power Switch Module with Si SJ MOSFETs is showed in Figures 5, 15, 16. Power Switch Module consists of power

FET devices and additional components which are necessary for correct operation.

Power Switch Module is designed for Silicon Power MOSFETs in small SMD package so-called the Power88. In Figure 6 is Power Switch module schematic, where M2 is the low side switch of PFC front stage, M4 and M5 create LLC half-bridge stage. C3, C4, C5, C6 and C7 are HF decoupling MLCC capacitors with same function as afore mentioned. Q1, Q2, Q6 forms emitter followers with Vcc decoupling capacitors C1, C2 and C41. Emitter followers provide buffering of driving signal in case of need – they can be assembled on purpose. Paralleled resistor–diode pairs (D14–R29, D1–R1, D2–R6) set switching slopes of MOSFETs and this way improving EMI signature.

Exchange of Power Switch Modules Important notes

– Power Switch Modules can be exchanged, but specific conditions must be satisfied due to operation differences:

Silicon MOSFETs requirements:

- Higher magnetizing current (compare to GaN) to achieve ZVS → Lower magnetizing inductance because of higher output capacitance
- Maximum needed Dead–time up to 500ns
- Maximum switching Frequency is limited from to 420 – 450kHz @Light–load – it is given by used MOSFET parameters
- Dedicated NCP1399 setting is needed for Si MOSFETs board option

GaN FETs requirements:

- Lower magnetizing current (compare to Si MOSFETs) to achieve ZVS → Higher magnetizing inductance, less conduction losses
- Maximum needed Dead–time ~200ns
- Frequency is limited by IC controller
- Dedicated NCP1399 setting is needed for GaN MOSFETs board option

To summarize: the LLC controller has to be replaced and air gap in the LLC transformer increased when Switching Module is changed from GaN to → Si type.

Control Module – (Figures NO TAG, NO TAG, 13, 14) integrates the PFC controller NCP1615, the LLC controller NCP1399 and secondary side CV/CC controller NCP4353 in one PCB. Control module is designed in such a way, that each component is placed to its dedicated controller as close as possible. Another design strategy was to move all signal processing components to the Control Module, except the high voltage circuitries for example bulk voltage feedback divider. Module also contains two optocouplers, first one output is used for voltage feedback loop. IC1 – NCP4353 (Figure NO TAG) senses output voltage using resistor divider R43, R44 and R45 and transfers this information via optocoupler U3 to primary side, to the U2 – NCP1399, which regulates switching frequency according to feedback and current sense signals. Second optocoupler is dedicated to output overvoltage protection (OVP). As soon as output

voltage reaches ~21V, optocoupler U4 pulls up OVP/OTP pin of U2 and activates OVP. Output OVP level and response is defined by zener diode D5, resistors R30, R31 and capacitor C21.

The LLC primary stage is formed by half-bridge, which is located on the Power switch Module, split resonant tank capacitors C15–C16, clamping diode D13, resonant inductor L5 (in case of discrete resonant transformer implementation) and transformer TR1. The resonant capacitor voltage divided down by R20, R21, C12, C13, C14, C19, C20, C21, C22, D11 and D12 and provides information about transformer current for NCP1399. Divider serves as current feedback loop and also sets adapter output current limit.

The Synchronous Rectifier Module (Figures 6, 17, 18) consists of two Single N–Channel SO–8FL Logic Level 60V MOSFETs Q1 and Q2, two synchronous rectifier (SR) controllers IC1–2 NCP43080 (or similar part from NCP430x family) and HF decoupling MLCC capacitors C3–8. RC snubber circuits, composed as R1–C1 and R2–C2, are connected across the drain and the source of each MOSFET, to protect them against voltage spikes. C9–11 and R6–7 are components use to filtering and HF decoupling supply voltage for both SR controllers. R4 (R9) and R5 (R8) serve to set minimum ON and minimum OFF switching times of SR controller. Automatic Light Load and Disable mode (LLD pin) is input modulates the driver clamp level and/or turns the driver off during light load conditions. This feature helps to reduce No–load consumption and improves Light–load efficiency. In Figure 6, the Light–Load Detection Circuitry is formed by resistors R11–14, ceramic capacitors C12, C13 and diodes D1–2. If there is a certain reason to not use LLD feature, use R3 (R10) zero ohms to disable it. Then in this situation Light–Load Detection Circuitry doesn't have to be assembled. When using NCP4306, R3 (R10) resistors can set specific timing of Automatic LLD or disable it fully and external Light–Load Detection Circuitry is not needed anymore. For more detail please see each device specific datasheet.

The regulation of output voltage is ensured by the regulator IC1–NCP4353 (see Figure NO TAG), which provides integrated voltage feedback regulation, replacing traditional shunt regulator. The device is capable of detecting “no–load” conditions and inserts the power supply into a low consumption OFF–mode. IC1 also includes a current regulation loop in addition to voltage regulation. These possibilities are included in design of PCBs, but demo–board is not utilized them. The optocoupler U3 is driven via resistor R29, which determines the feedback loop gain. Resistor R46 biases the NCP4353 in case that there is no current flowing through the optocoupler U3. The voltage feedback loop compensation network is created by resistors R39, R42 capacitors C24, C25. The value of output voltage is set up by voltage divider comprised of resistors R43, R44, R45.

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Coupling between primary and secondary is ensured by the Y-capacitor CY1, which is connected between secondary ground and primary bulk voltage. Similar functionality have CY2 and CY3, which are placed between input terminals (L, N) and their center point is connected to PE earth terminal. PE-A and PE-B allow making the

connection between secondary ground GND and input earth terminal (PE). The connection should be made by awg 18 or 0.75 mm² wire with optionally threaded ferrite bead.

This configuration of CY1–3 helps to improve the EMI signature of the converter and pass legislation EMI emission limits.

PBC Layout

The PCB is made as a double layer FR4 board with 35µm copper cladding.

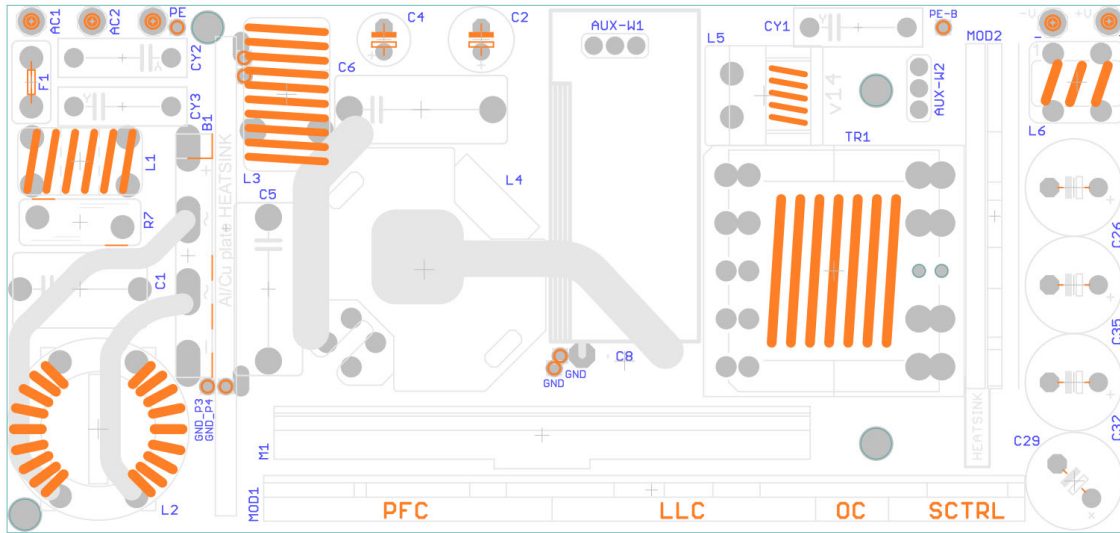


Figure 8. Evaluation Board – Top Side Components

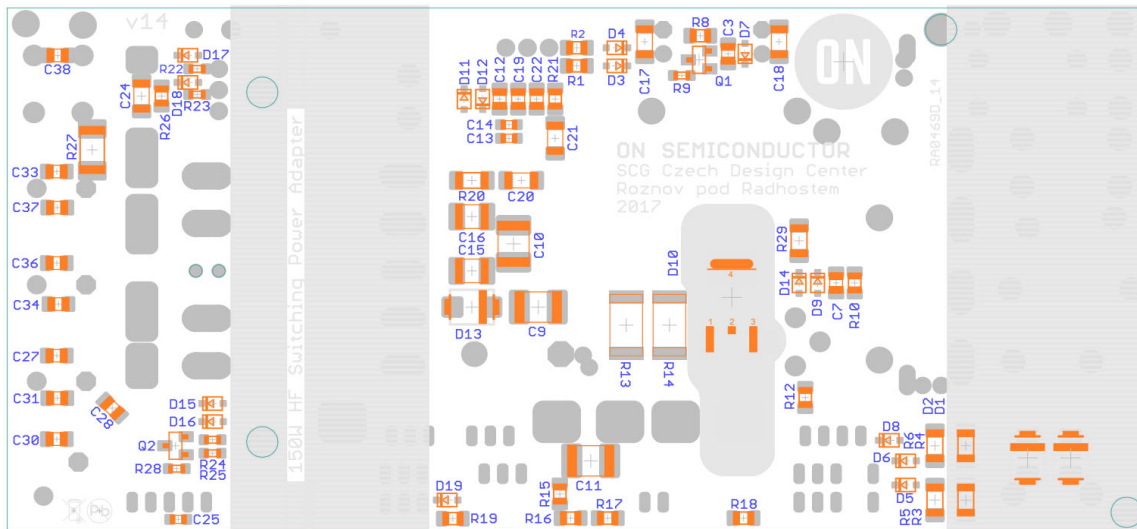


Figure 9. Evaluation Board – Bottom Side Components

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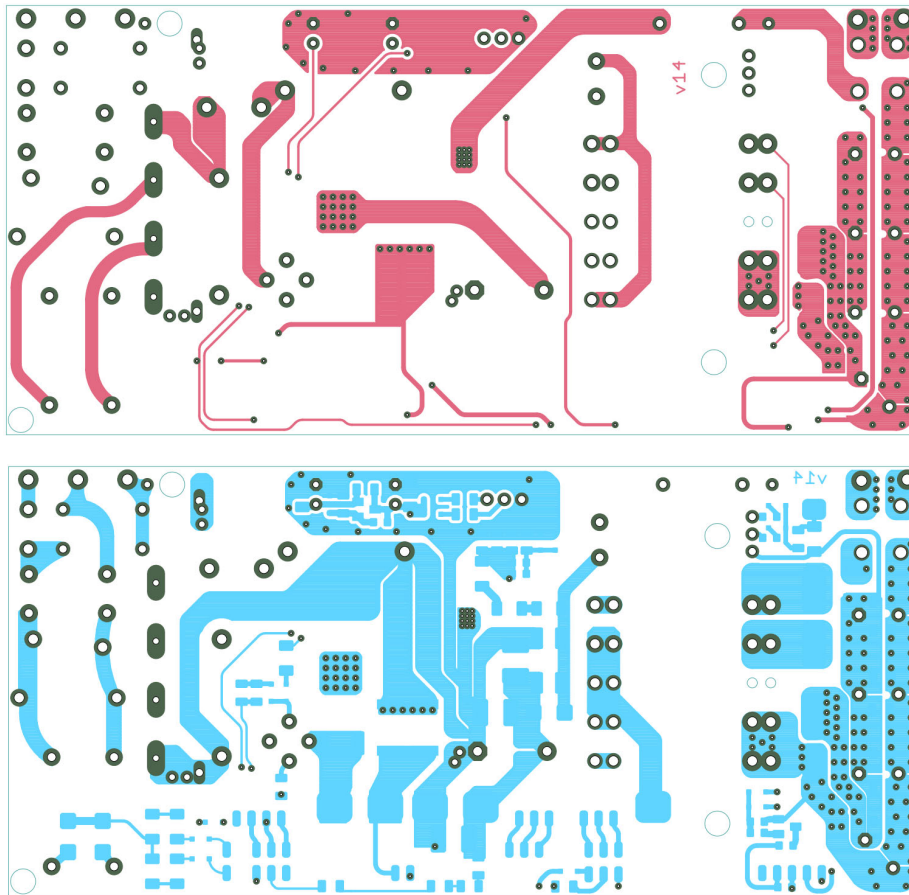


Figure 10. Evaluation Board – Top Layer Red, Bottom Layer Blue



Figure 11. Evolution Board Photograph – Bottom Side



Figure 12. Evolution Board Photograph – Top View

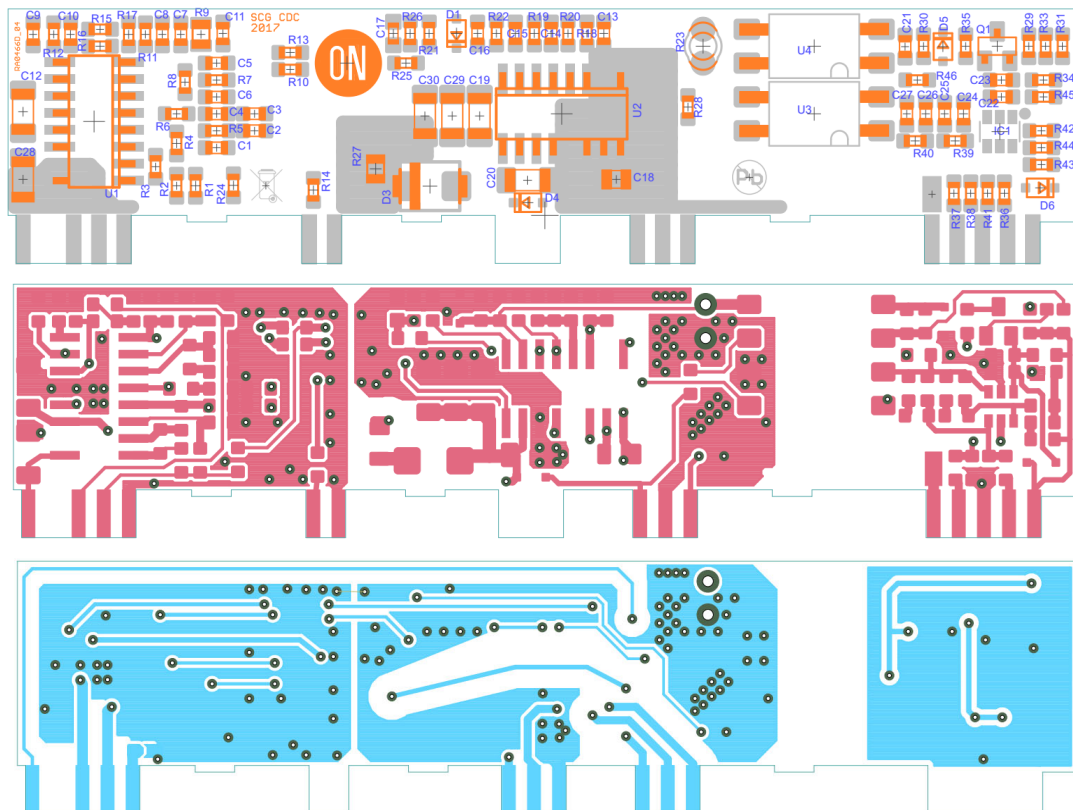


Figure 13. Control Module – Top Side Components, Top Layer – Red, Bottom Layer – Blue

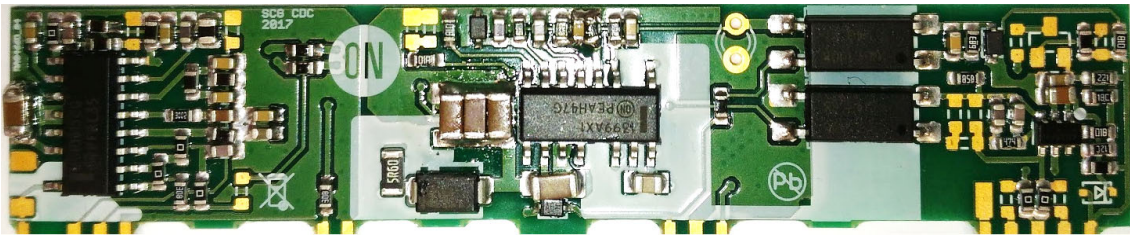


Figure 14. Control Module Photograph

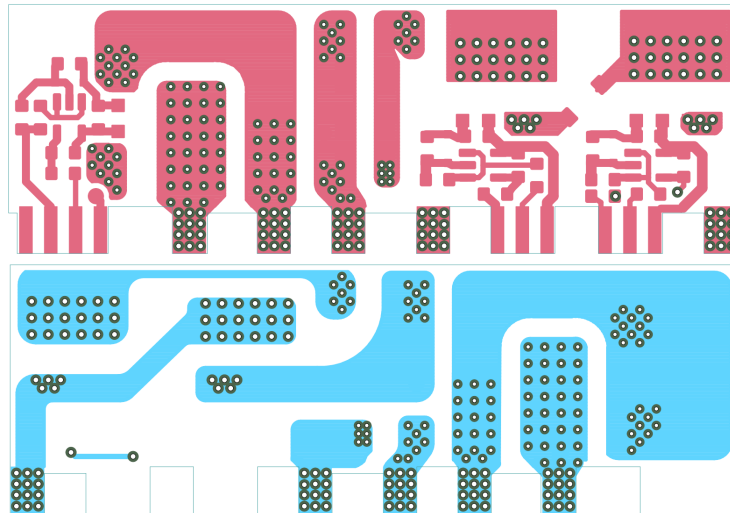
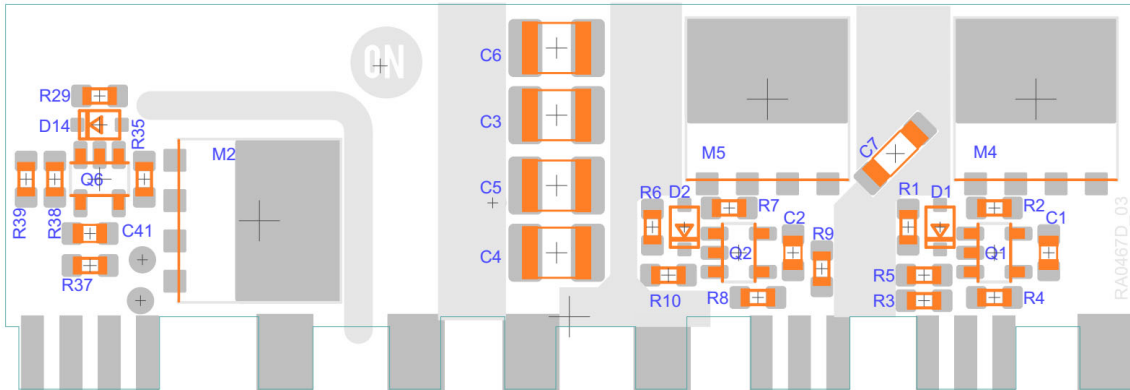


Figure 15. Power Switch Module, Top Side Components, Top Layer – Red,
Bottom Layer – Blue

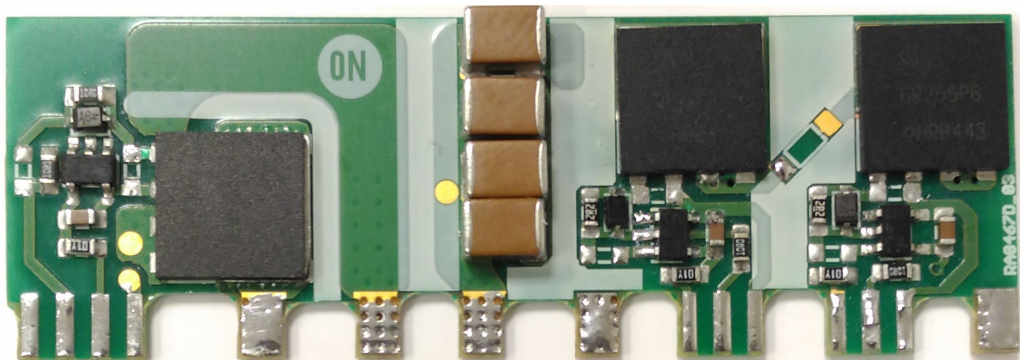


Figure 16. Power Switch Module Photograph

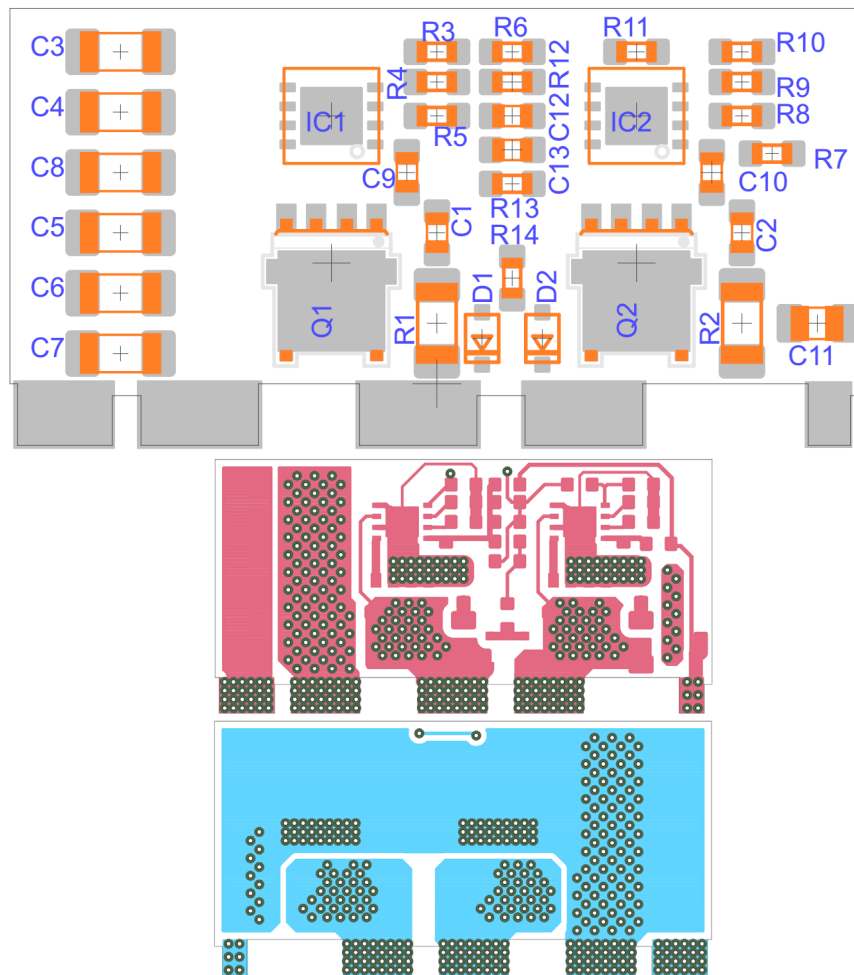


Figure 17. SR Module, Top Side Components, Top Layer – Red, Bottom Layer – Blue

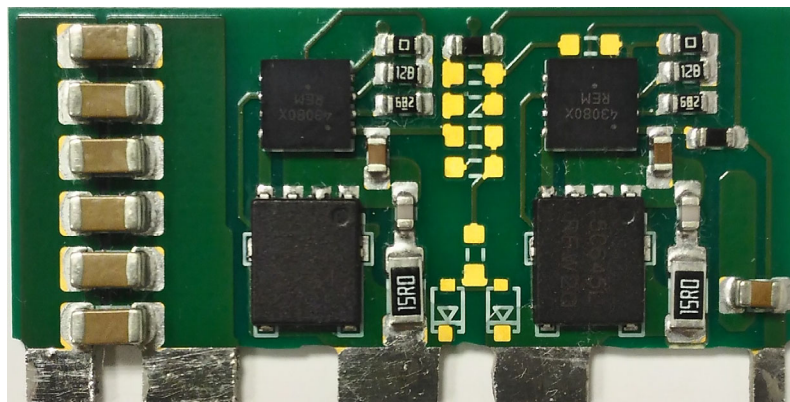


Figure 18. SR Module Photograph

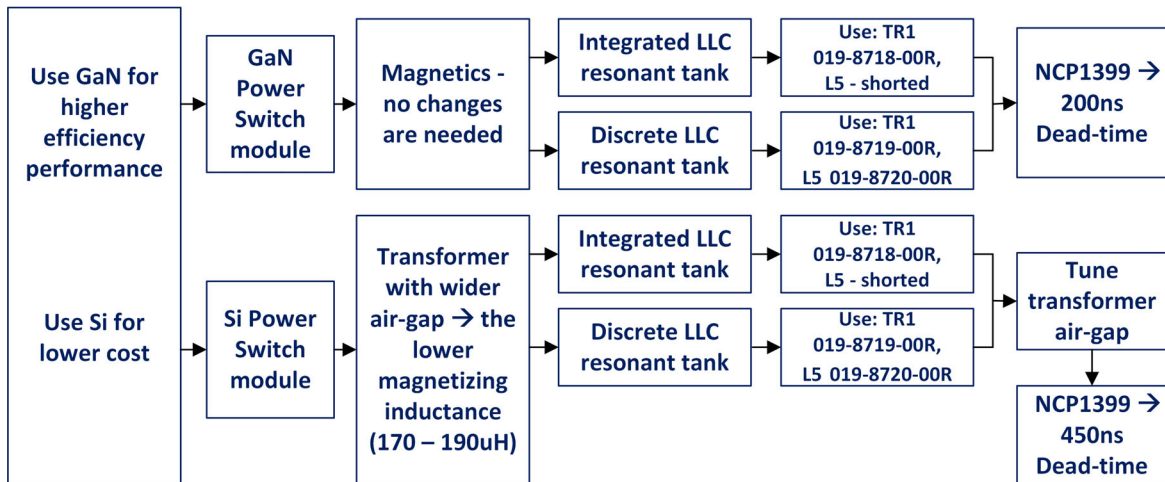
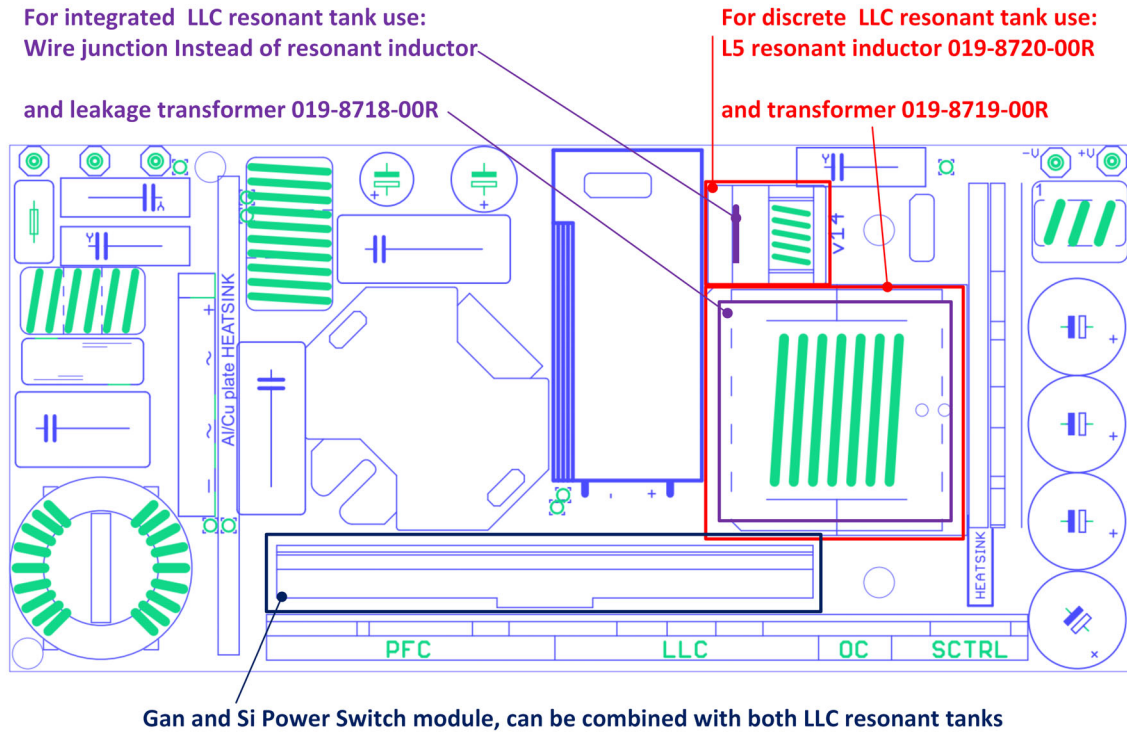


Figure 19. Resonant Tank Composition And Power Switch Module Selection Procedures

MEASUREMENTS

The measurements show the performance of High Power Density Demo-board.

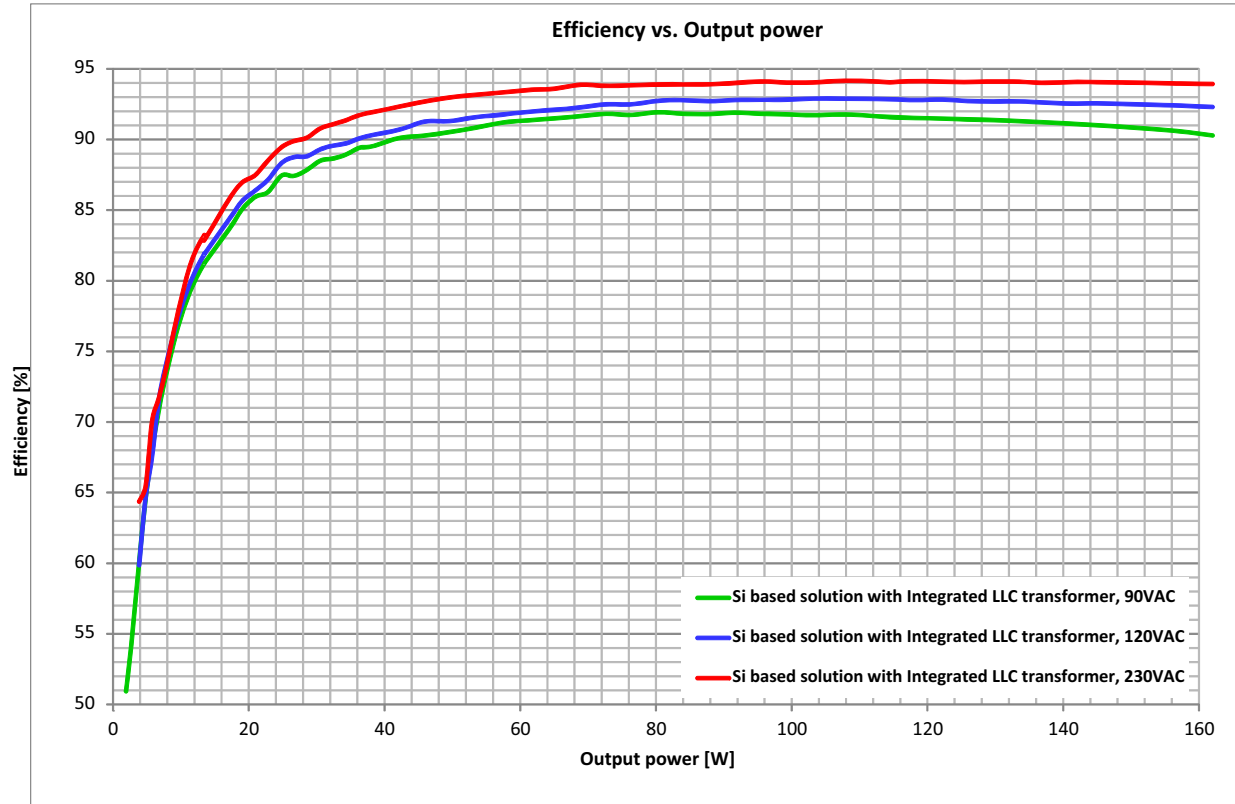


Figure 20. Efficiency Graph Of High Power Density Demo-Board*

NOTES: *Measured with IPL60R255P6 placed in PFC and LLC stages

Table 2. EFFICIENCY TABLE

Output power level [%]		10%	25%	50%	75%	100%	Max efficiency	Calculated 4-point avg. efficiency
Efficiency [%] @ Input voltage [V _{RMS}]	90	81.24	89.42	91.74	91.72	90.90	91.93	91.14
	120	81.90	90.07	92.49	92.88	92.52	92.90	92.17
	230	82.87	91.72	93.80	94.14	94.03	94.15	93.57

Table 3. STANDBY POWER TABLE

Input voltage [V _{ms}]	90	120	230	265
Standby power [mW]	149 (Note 1, 2)	152 (Note 1, 2)	150 (Note 1, 2)	150 (Note 1, 2)

1. Measured with Tektronix PA1000 Power Analyzer and the integration mode was used.
2. Still exists place for no-load optimisation.

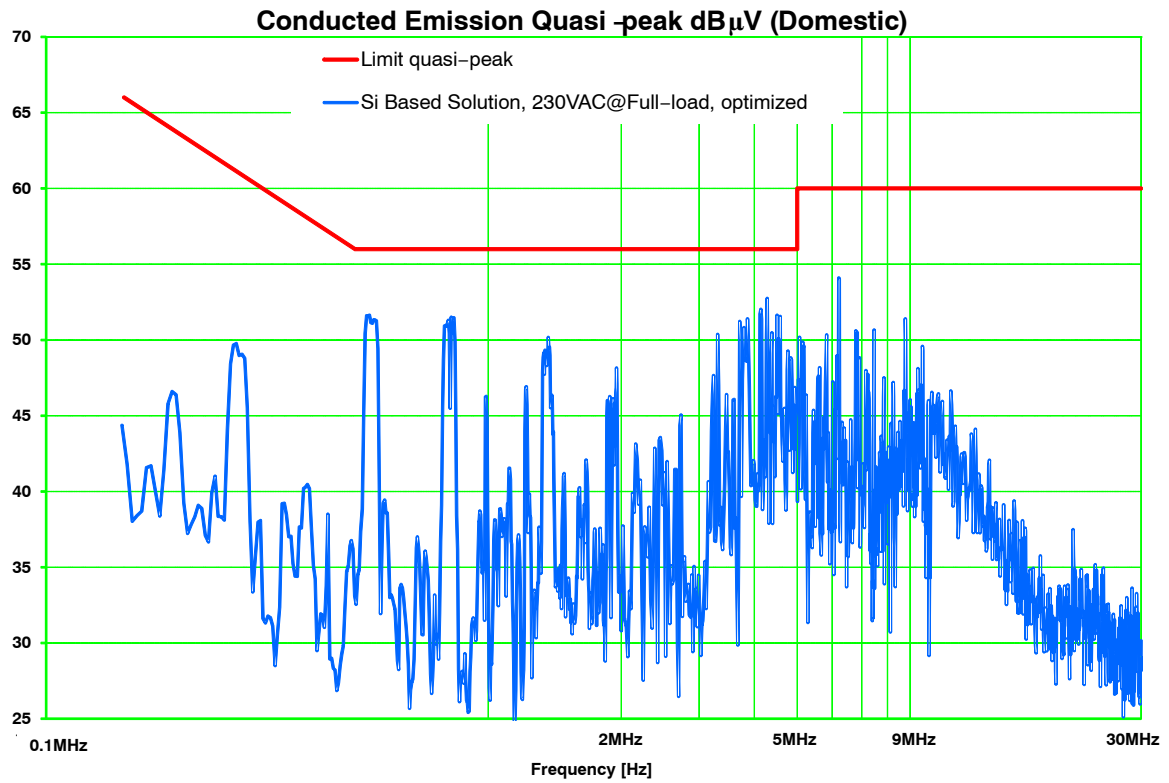


Figure 21. EMI Signature Comparison @ 230 VAC (Measured MAX Peak)

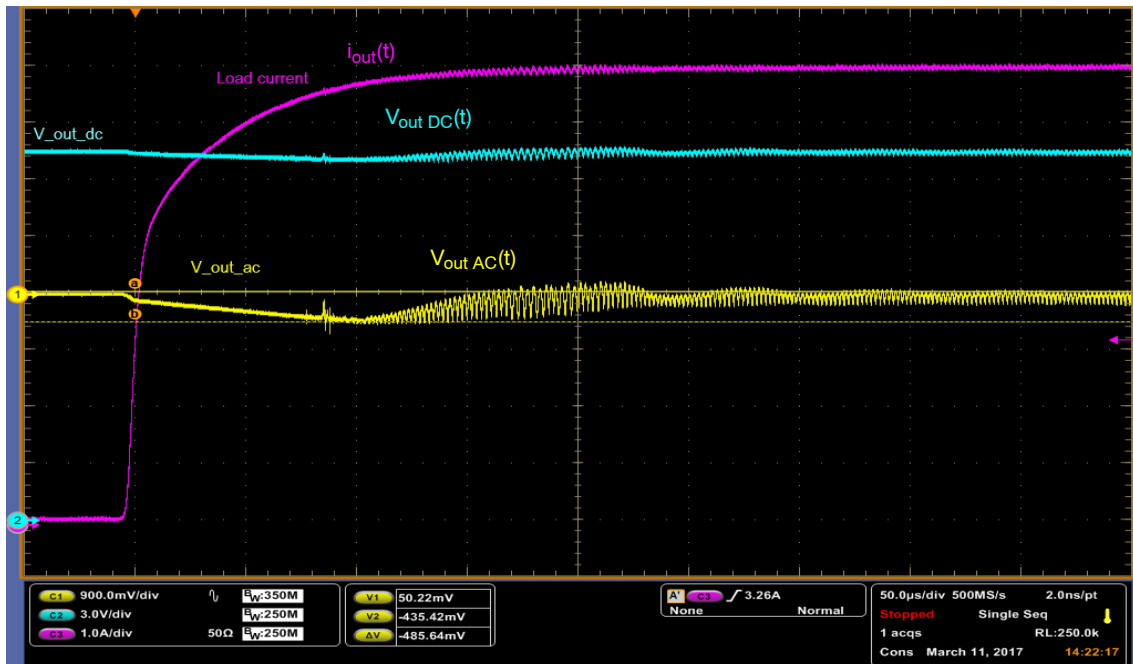


Figure 22. Transition Response – $I_{OUT} = 0\text{ A to }8\text{ A}$, $V_{IN} = 120\text{ V}$,

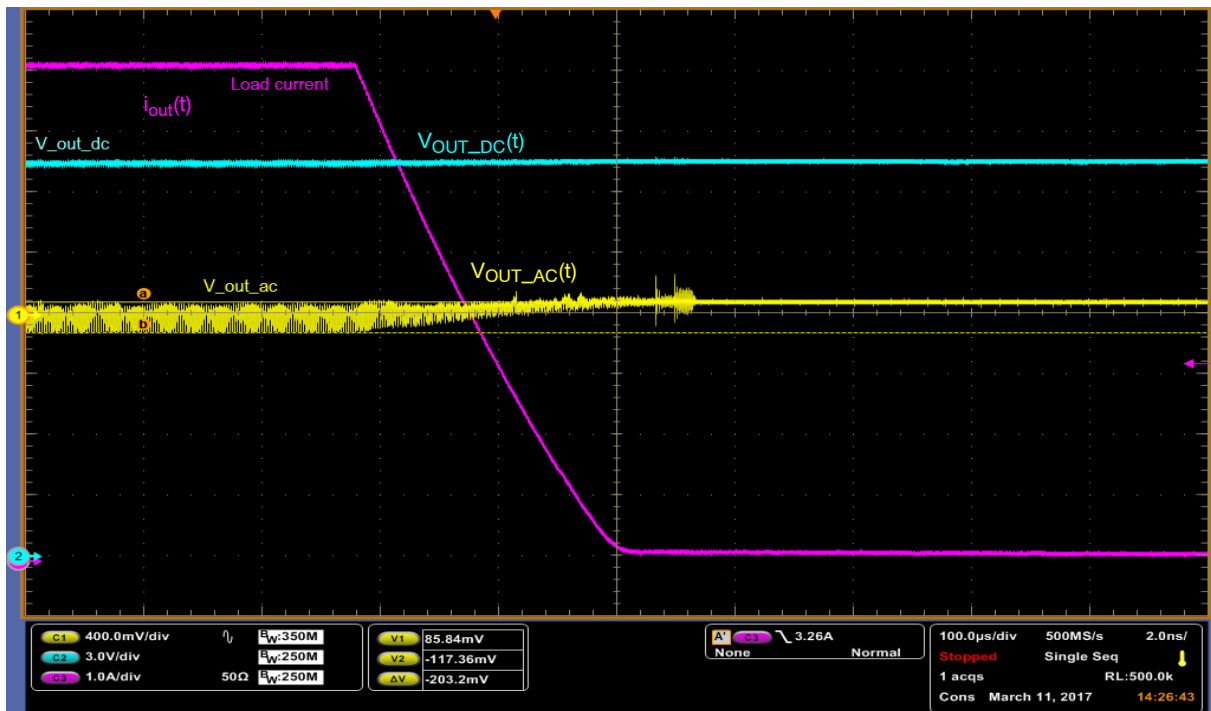


Figure 23. Transition Response – $I_{OUT} = 8A$ to $0A$, $V_{IN} = 120V$,

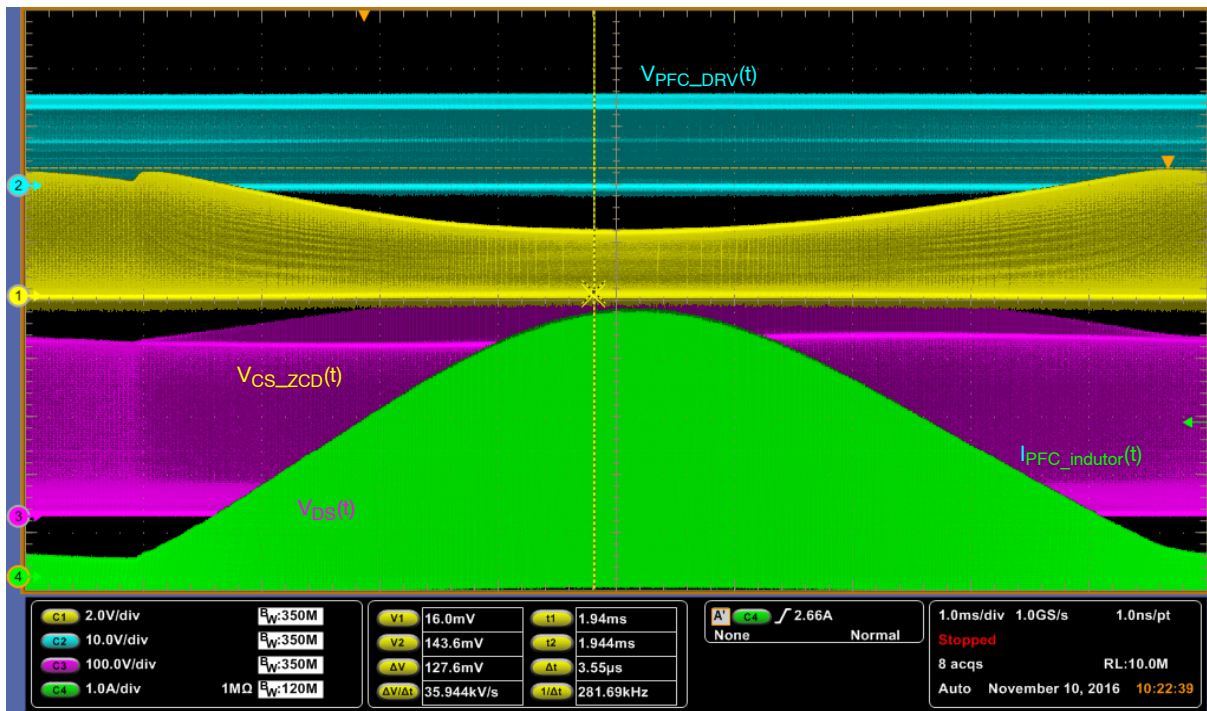


Figure 24. PFC – Input Current Modulation, $I_{OUT} = 7A$, $V_{IN} = 120V$,

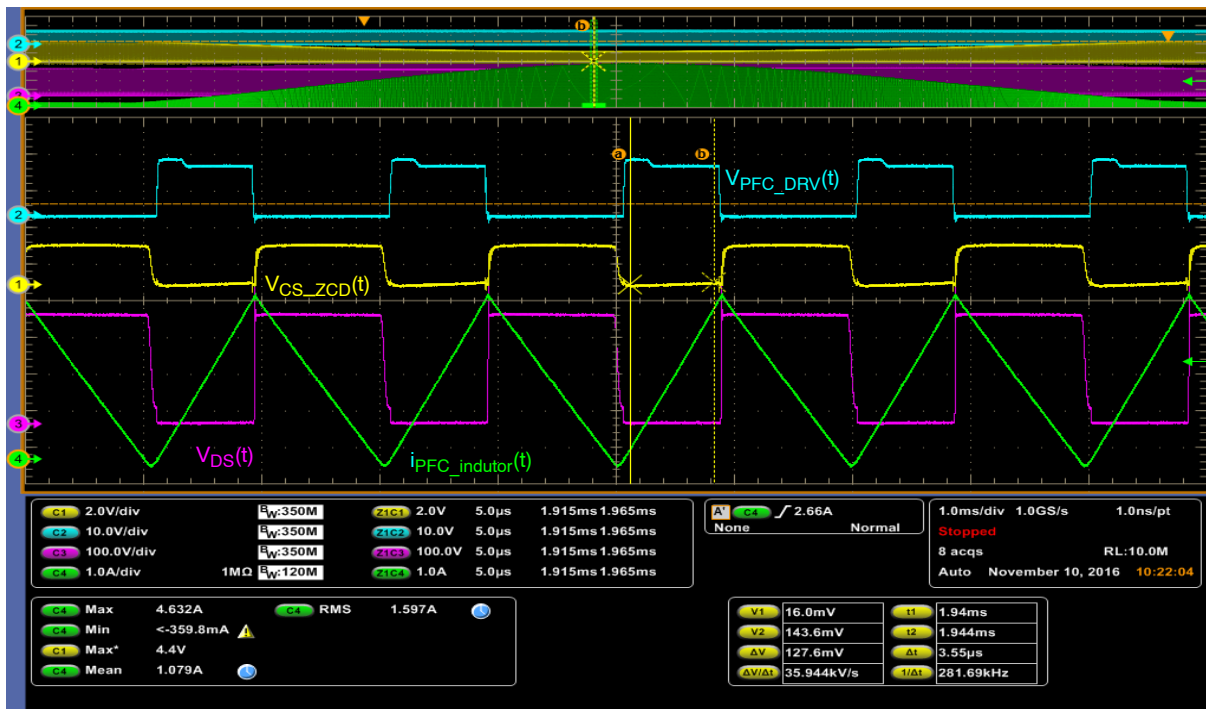


Figure 25. PFC Operating Waveforms, $I_{OUT} = 7\text{ A}$, $V_{IN} = 120\text{ V}$,

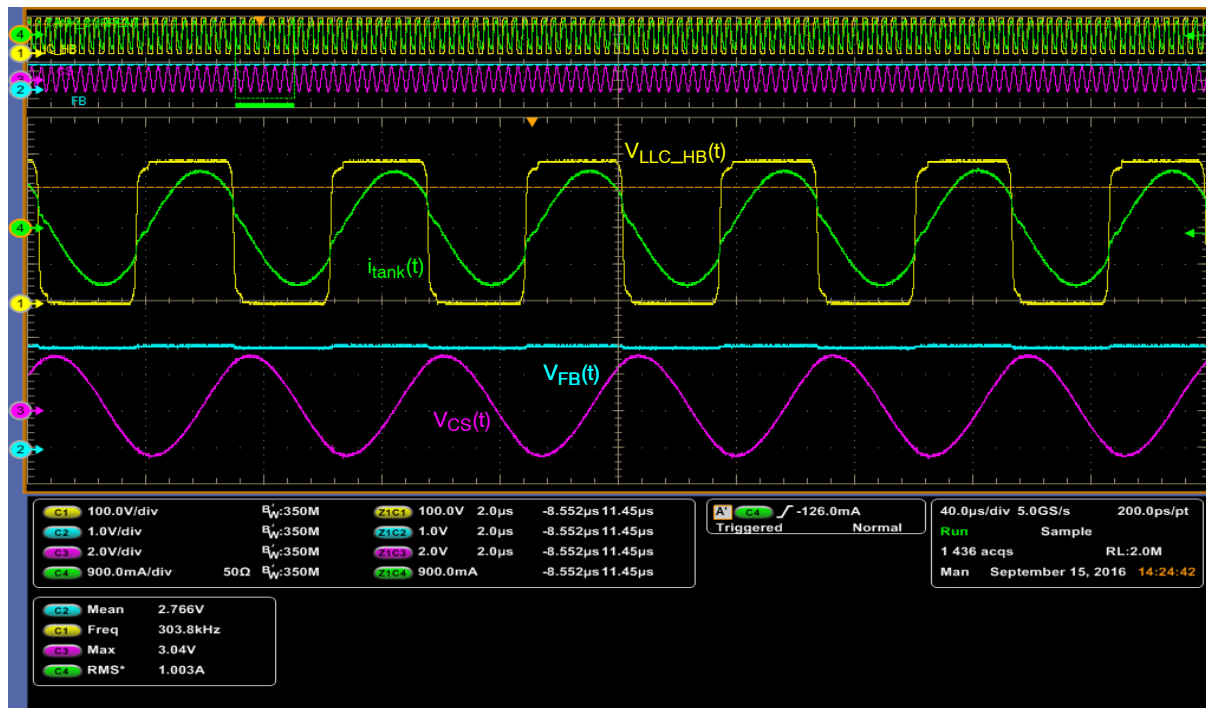


Figure 26. LLC – Stage Normal Operation Waveforms, $I_{OUT} = 8\text{ A}$ (Full-load)

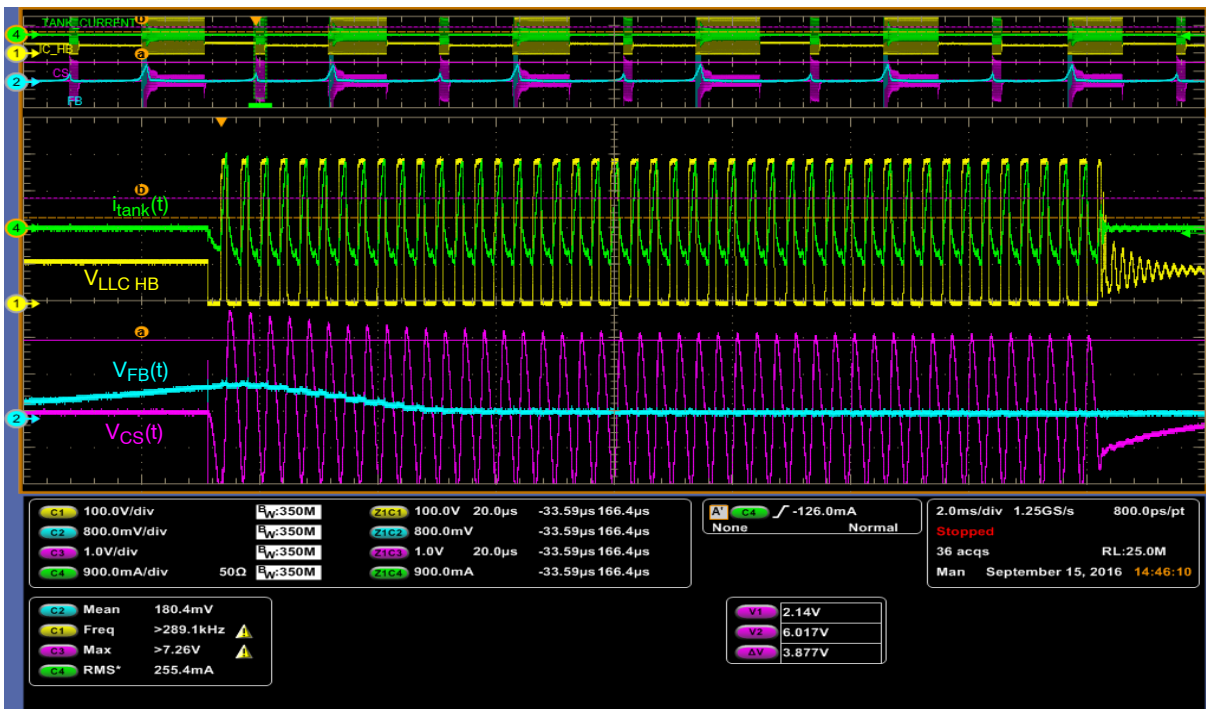


Figure 27. LLC Stage SKIP MODE Operation Waveforms, $I_{OUT} = 600 \text{ mA}$



Figure 28. Synchronous Rectifier Operating Waveforms – SKIP MODE $I_{OUT} = 100 \text{ mA}$, $V_{IN} = 120 \text{ V}$,



Figure 29. Synchronous rectifier operating waveforms, $I_{OUT} = 8\text{ A}$, $V_{IN} = 120\text{ V}$,

Literature

High Voltage Active X2 Power Factor Controller:

NCP1615: http://www.onsemi.com/pub_link/Collateral/NCP1615-D.PDF

High Performance Current Mode Resonant Controller with Integrated High Voltage Drivers:

NCP1399: http://www.onsemi.com/pub_link/Collateral/NCP1399-D.PDF

Secondary Side Synchronous Rectifier Controllers:

NCP43080: http://www.onsemi.com/pub_link/Collateral/NCP43080-D.PDF

NCP4305: <http://www.onsemi.com/pub/Collateral/NCP4305-D.PDF>

Secondary Side SMPS OFF Mode Controller for Low Standby Power

NCP4353: <http://www.onsemi.com/pub/Collateral/NCP4353-D.PDF>

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Table 4. BILL OF MATERIALS

POWER BOARD v14								
Parts	Qty	Description	Value	Tol-er-anc-e	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
B1	1	Bridge Rectifier	KBJ608G	–	THP	Diodes Inc.	KBJ608G	YES
C1	1	Capacitor	330nF/275V ac	10%	THP	Wurth Elektronik	890 334 024 003	NO
C7, C12, C19	1	MLCC SMD	NU	–	C0805	–	–	–
C13, C14	1	MLCC SMD	NU	–	C0603	–	–	–
C25	2	MLCC SMD	NU	–	C0603	–	–	–

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Table 4. BILL OF MATERIALS

POWER BOARD v14								
Parts	Qty	Description	Value	Tol-er-ance	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
C15, C16	2	MLCC SMD	3.9nF/630V	5%	C1206	TDK	CGA5F4C0G2J392J085AA	NO
C17, C18	2	MLCC SMD	1uF/35V	20%	C1206	MULTICOMP	MC1206F105Z250CT	YES
C2	1	Electrolytic Capacitor	220uF/35V	20%	THP	YAGEO	SY035M0220B3S-0815	
C20, C21	2	MLCC SMD	100p/1kV	5%	C1206	Murata	GRM31A5C3A101JW01D	NO
C22	1	MLCC SMD	3.9nF/25V	5%	C0805	Various	Various	YES
C24	1	MLCC SMD	NU	-	C1206	-	-	-
C26, C29, C32, C35	4	Electrolytic Capacitor	680uF/25V	20%	THP	Wurth Elektronik	860 020 475 016	YES
			330uF/25V	20%			870 025 575 009	
C28, C31, C34, C37, C38	4	MLCC SMD	330nF/25V	20%	C1206	Murata	GRM319R71E334KA01D	YES
C27, C30, C33, C36	4	MLCC SMD	100nF/35V	20%	C1206	Various	Various	YES
C3	1	MLCC SMD	10nF	10%	C0805	Various	Various	YES
C4	1	Electrolytic Capacitor	47uF/25V	10%	E2,5-6	Nippon Chemi-con	ELXZ250ETD470MEB5D	YES
C5, C6	2	MKP Film Capacitors	1uF/450Vdc	5%	THP	Panasonic	ECW-FD2W105J	YES
C8	1	Electrolytic Capacitor	120u/420V	20%	THP	Rubycon	420CXW120MEFR16x35	YES
C9, C10, C11	3	MLCC SMD	470nF/450V	20%	C1812	TDK	C4532X7T2W474K230KA	YES
CY1	1	Ceramic Capacitor - Y	2.2n/Y1	20%	THP	Vishay	VY1222M43Y5UC63V0	YES
CY2, CY3	2	Ceramic Capacitor - Y	1.5n/Y1	20%	THP	Vishay	VY1152M35Y5UC63V0	YES
D1, D2	2	Diode SMD	MRA4007T3G	-	SMA	ON Semiconductor	MRA4007T3G	NO
D10	1	Diode SMD	MURHD560T4G	-	DPACK	ON Semiconductor	MURHD560T4G	NO
D13	1	Diode SMD	MURA160	-	SMA	ON Semiconductor	MURA160T3G	NO
D15, D16	3	Diode SMD	NU	-	SOD323	-	-	-
D3, D4, D14	3	Diode SMD	MBR2H100SFT3G	-	SOD123	ON Semiconductor	MBR2H100SFT3G	NO
D8	1	Diode SMD	MUST BE SHORTED	-	SOD323	-	-	-
D19	1	Diode SMD	NRS034HT1G	-	SOD323	ON Semiconductor	NRS034HT1G	NO

Table 4. BILL OF MATERIALS

POWER BOARD v14								
Parts	Qty	Description	Value	Tol-er-ance	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
D11, D12	9	Diode SMD	NU	–	SOD323	–	–	–
D9, D17, D18,	9	Diode SMD	BAS16HT1G	–	SOD323	ON Semiconductor	BAS16HT1G	NO
D5, D6	2	Diode SMD	BAS20HT1G	–	SOD323	ON Semiconductor	BAS20HT1G	NO
D7	1	Zener Diode SMD	MM3Z20VT1G	–	SOD323	ON Semiconductor	MM3Z20VT1G	NO
F1	1	Fuse	T5A	–	THP	Bussmann / Eaton	SS-5H-5A-BK	YES
HEATSINK	1	HEATSINK 50x16x2 mm	Aluminium heatsink	–	–	–	–	–
L1 (Note 4)	1	EMI Filter	NU	–	–	–	–	–
L2	1	EMI Filter	10mH	20%	THP	Würth Elektronik	744 823 210	NO
L3	1	EMI Filter	90uH	20%	THP	Würth Elektronik	744 701 3	NO
L4	1	PFC INDUCTOR	150uH	20%	RM10	Precision Inc	019-8650-03R	NO
L5 (Note 3)	1	LLC resonant inductor	51uH	20%	RM5	Precision Inc	019-8720-00R	NO
L6 (Note 4)	1	Common mode inductor	NU	–	THP	–	–	–
L7, L8 (Note 4)	2	EMI Filter, Ferrite Bead	39Ohm@25 MHz	–	THP	Elektronik Würth	742 700 713	NO
Q1	1	N-CHANNE L MOS FET	NVR5198NL	–	SOT23	ON Semiconductor	NVR5198NL	NO
Q2	1	PNP Transistor	NU	–	SOT23	–	–	–
R1, R2	2	Resistor SMD	2R2	1%	R0805	Various	Various	YES
R12, R19, R26	3	Resistor SMD	0R	–	R0805	Various	Various	YES
R13, R14	2	Resistor SMD	200m	5%	R6332	Various	Various	YES
R15, R16, R17, R18	4	Resistor SMD	3M3	1%	R0805	Various	Various	YES
R20	1	Resistor SMD	1R	1%	R1206	Various	Various	YES
R21	1	Resistor SMD	910	1%	R0805	Various	Various	YES
R22, R23	2	Resistor SMD	2R	1%	R0603	Various	Various	YES
R24, R25, R28	3	Resistor SMD	NU	–	R0603	–	–	–

Table 4. BILL OF MATERIALS

POWER BOARD v14								
Parts	Qty	Description	Value	Tol-er-ance	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
R27	1	Resistor SMD	0R	–	R2010	Various	Various	YES
R29	1	Resistor SMD	2R2	–	R1206	Various	Various	YES
R3, R4, R5, R6	4	Resistor SMD	1k2	1%	R1206	Various	Various	YES
R7	1	Varistor	275 Vac	–	THP	Würth Elektronik	820 512 711	YES
R8	1	Resistor SMD	NU	–	R0805	–	–	–
R9	1	Resistor SMD	12k	1%	R0603	Various	Various	YES
R10	1	Resistor SMD	5k6	1%	R0805	Various	Various	YES
TR1 (Note 3)	1	LLC Transformer	–	–	–	Precision Inc	019–8719–00R / 019–8718–00R	NO

3. Follow Procedure in Figure 19

4. Optional component, can be used to tune the Demo-board EMI signature

Table 4. BILL OF MATERIALS

CONTROL MODULE V4								
Parts	Qty	Description	Value	Tol-er-ance	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
C1, C16	2	MLCC SMD	100pF	20%	C0603	Various	Various	YES
C10	1	MLCC SMD	3.3pF	20%	C0603	Various	Various	YES
C11, C26, C27	3	MLCC SMD	NU	–	C0603	–	–	–
C12	1	MLCC SMD	10uF/25V	20%	C1206	Various	Various	YES
C15	1	MLCC SMD	470pF	20%	C0603	Various	Various	YES
C17	1	MLCC SMD	NU	–	C0603	–	–	–
C18	1	MLCC SMD	100nF/25V	20%	C0805	Various	Various	YES
C19, C20, C29, C30	4	MLCC SMD	47u/25V	20%	C1206	TDK	C3216X5R1E4 76M160AC	
C2, C5, C13, C14, C21	5	MLCC SMD	10nF	20%	C0603	Various	Various	YES
C22	1	MLCC SMD	1uF/25V	20%	C0603	Various	Various	YES
C23	1	MLCC SMD	100nF/25V	20%	C0603	Various	Various	YES
C24	1	MLCC SMD	22pF	20%	C0603	Various	Various	YES
C25	1	MLCC SMD	330pF	20%	C0603	Various	Various	YES
C28	1	MLCC SMD	NU	–	C1206	–	–	–
C3, C6	2	MLCC SMD	220nF	10%	C0603	Various	Various	YES
C4	1	MLCC SMD	2.2uF	20%	C0603	TDK	C1608X5R1E2 25K080AB	YES

Table 4. BILL OF MATERIALS

CONTROL MODULE V4								
Parts	Qty	Description	Value	Tol-er-ance	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
C7	1	MLCC SMD	1nF	10%	C0603	Various	Various	YES
C8, C9	2	MLCC SMD	100nF	10%	C0603	Various	Various	YES
D1	1	Zener Diode	MM3Z4V3T1G	–	SOD323	ON Semiconductor	MM3Z4V3T1G	NO
D3	1	Diode SMD	MURA160	–	SMA	ON Semiconductor	MURA160T3G	NO
D4	1	Diode SMD	BAS16HT1G	–	SOD323	ON Semiconductor	BAS16HT1G	NO
D5	1	Zener Diode SMD	MM3Z20VT1G	–	SOD323	ON Semiconductor	MM3Z20VT1G	NO
D6	1	Diode	NU	–	SOD323	–	–	–
IC1	1	Secondary side CV/CC controller	NCP4353A	–	TSOP6	ON Semiconductor	NCP4353ASNT1G	NO
Q1	1	PNP Transistor	NU	–	SOT23	–	–	–
R1, R3, R4, R12, R38, R41	6	Resistor SMD	0R	–	R0603	Various	Various	YES
R10, R43	2	Resistor SMD	200k	1%	R0603	Various	Various	YES
R11	1	Resistor SMD	62k	1%	R0603	Various	Various	YES
R15	1	Resistor SMD	0R	1%	R0603	Various	Various	YES
R16	1	Resistor SMD	910R	1%	R0603	Various	Various	YES
R17, R24, R26, R33, R35, R36, R37, R40	8	Resistor SMD	NU	–	R0603	–	–	–
R18	1	Resistor SMD	360k	1%	R0603	Various	Various	YES
R2	2	Resistor SMD	3k9	1%	R0603	Various	Various	YES
R14	2	Resistor SMD	4k7	1%	R0603	Various	Various	YES
R20	1	Resistor SMD	910k	1%	R0603	Various	Various	YES
R21, R31, R42	3	Resistor SMD	1k	1%	R0603	Various	Various	YES
R22, R44	2	Resistor SMD	13k	1%	R0603	Various	Various	YES
R23	1	NTC Thermistor	330k	1%	Through Hole	VISHAY	NTCLE100E3334JB0	YES

EVBUM2516/D

Table 4. BILL OF MATERIALS

CONTROL MODULE V4								
Parts	Qty	Description	Value	Tol-er-anc-e	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
R25	1	Resistor SMD	100R	1%	R0603	Various	Various	YES
R27	1	Resistor SMD	5R6	1%	R0805	Various	Various	YES
R28	1	Resistor SMD	5k1	1%	R0603	Various	Various	YES
R29	1	Resistor SMD	750R	1%	R0603	Various	Various	YES
R30	1	Resistor SMD	68k	1%	R0603	Various	Various	YES
R34	1	Resistor SMD	220R	1%	R0603	Various	Various	YES
R39	1	Resistor SMD	470k	1%	R0603	Various	Various	YES
R45	1	Resistor SMD	15k	1%	R0603	Various	Various	YES
R46	1	Resistor SMD	7k5	1%	R0603	Various	Various	YES
R5	1	Resistor SMD	83.5k	1%	R0603	Various	Various	YES
R6	1	Resistor SMD	27k	1%	R0603	Various	Various	YES
R13, R19	3	Resistor SMD	30k	1%	R0603	Various	Various	YES
R7	1	Resistor SMD	270k	1%	R0603	Various	Various	YES
R8	1	Resistor SMD	120k	1%	R0603	Various	Various	YES
R9	1	NTC Thermistor	330k	5%	R0805	VISHAY	NTCS0805E33 34JHT	YES
U1	1	PFC Controller	NCP1615C2 DR2G	–	SO15	ON Semiconductor	NCP1615C2DR 2G	NO
U2*	1	LLC Controller	NCP1399	–	SOIC16	ON Semiconductor	NCP1399*	NO
U3, U4	2	Optocoupler	TCLT1008	–	DIP4	VISHAY	TCLT1008TR–ND	NO

Table 4. BILL OF MATERIALS

SI MOSFETS MODULE V3								
Parts	Qty	Description	Value	Tol-er-anc-e	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
C1, C2, C41	3	MLCC SMD	1uF/25V	10%	C0603	Various	Various	YES
C3, C4, C5, C6	4	MLCC SMD	100nF/450V	20%	C1206	TDK	C3216X7T2W1 04K160AA	YES
C7	1	MLCC SMD	NU	10%	C1206	–	–	–

Table 4. BILL OF MATERIALS

SI MOSFETS MODULE V3								
Parts	Qty	Description	Value	Tol-er-anc-e	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
D1, D2, D14	3	Diode SMD	BAS16HT1G	–	SOD323	ON Semiconductor	BAS16HT1G	NO
M2, M4, M5	3	Power MOSFET	FCMT199N60	–	POWE R88	Fairchild/ ON Semiconductor	FCMT199N60	YES
Q1, Q2, Q6	3	Bipolar transistor Totem-pole	–	–	SC74A	–	–	–
R1, R6	2	Resistor SMD	2R2	1%	R0603	Various	Various	YES
R2, R7, R35	3	Resistor SMD	10k	1%	R0603	Various	Various	YES
R3, R8, R37	3	Resistor SMD	–	–	R0603	–	–	–
R4, R9, R29, R38	4	Resistor SMD	0R	–	R0603	Various	Various	YES
R5, R10, R39	3	Resistor SMD	0R	–	R0603	Various	Various	YES

Table 4. BILL OF MATERIALS

SR MODULE V4.2								
Parts	Qty	Description	Value	Tol-er-anc-e	Pack-age	Manufacturer	Manufacturer Part Number	Substitution Allowed
C1, C2	2	MLCC SMD	100pF/100V	20%	C0603	Various	Various	YES
C11	1	MLCC SMD	1u/25V	20%	C0805	Various	Various	YES
C12	1	MLCC SMD	22nF	20%	C0603	Various	Various	YES
C13	1	MLCC SMD	NU	–	C0603	–	–	–
C3, C4, C5, C6, C7, C8	6	MLCC SMD	1uF/25V	20%	C1206	MULTICOMP	MC1206F105Z250CT	YES
C9, C10	2	MLCC SMD	2.2uF	20%	C0603	TDK	C1608X5R1E225K080AB	YES
D1, D2	2	Diode SMD	BAS20HT1G	–	SOD323	ON Semiconductor	BAS20HT1G	NO
IC1, IC2	2	Synchronous rectifier controller	NCP43080	–	DFN-8	ON Semiconductor	NCP43080DMNTWG	NO
Q1, Q2	2	Power MOSFET	NVMFS5C670NL	–	SO8FL	ON Semiconductor	NVMFS5C670NL	YES
R1, R2	2	Resistor SMD	15R	1%	R1206	Various	Various	YES
R11	1	Resistor SMD	0R	–	R0603	Various	Various	YES
R12	1	Resistor SMD	47k	1%	R0603	Various	Various	YES
R13	1	Resistor SMD	0R	–	R0603	Various	Various	YES

Table 4. BILL OF MATERIALS

SR MODULE V4.2								
Parts	Qty	Description	Value	Tol- er- anc- e	Pack- age	Manufacturer	Manufacturer Part Number	Substitution Allowed
R14	1	Resistor SMD	430R	1%	R0603	Various	Various	YES
R3, R10	2	Resistor SMD	NU	–	R0603	–	–	–
R4, R9	2	Resistor SMD	1k3	1%	R0603	Various	Various	YES
R5, R8	2	Resistor SMD	6k8	1%	R0603	Various	Various	YES
R6, R7	2	Resistor SMD	5R1	1%	R0603	Various	Various	YES

5. All parts are Lead-free

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